NSN 5962-01-058-6737

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
660.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Radar set type an/aps-125
Features Provided:
Hermetically sealed and monolithic and programmable and programmed and w/enable and w/buffered output
Inclosure Material:
Ceramic
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Memory Device Type:
Rom
Special Features:
Bit pattern table no. 7
Test Data Document:
27963-57991100 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0